

# BLC10G22XS-400AVT

Power LDMOS transistor

Rev. 1 — 30 April 2018

AMPLEON

Product data sheet

## 1. Product profile

### 1.1 General description

400 W LDMOS packaged asymmetric Doherty power transistor for base station applications at frequencies from 2110 MHz to 2200 MHz.

**Table 1. Typical performance**

Typical RF performance at  $T_{case} = 25\text{ °C}$  in an asymmetrical Doherty production test circuit.

$V_{DS} = 28\text{ V}$ ;  $I_{Dq} = 800\text{ mA}$  (main);  $V_{GS(amp)peak} = 1.0\text{ V}$ , unless otherwise specified.

Test signal	f	$V_{DS}$	$P_{L(AV)}$	$G_p$	$\eta_D$	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
1-carrier W-CDMA	2110 to 2200	28	56	17.0	47.0	-29.6 <a href="#">[1]</a>

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01 % probability on CCDF.

### 1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- For RoHS compliance see the product details on the Ampleon website

### 1.3 Applications

- RF power amplifiers for base stations and multi carrier applications in the 2110 MHz to 2200 MHz frequency range

## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain2 (peak)		<p>aaa-014884</p>
2	drain1 (main)		
3	gate1 (main)		
4	gate2 (peak)		
5	source <a href="#">[1]</a>		
6	video decoupling (peak)		
7	video decoupling (main)		

[1] Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLC10G22XS-400AVT	-	air cavity plastic earless flanged package; 6 leads	SOT1258-4

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS(amp)main}$	main amplifier gate-source voltage		-6	+9	V
$V_{GS(amp)peak}$	peak amplifier gate-source voltage		-6	+9	V
$T_{stg}$	storage temperature		-65	+150	°C
$T_j$	junction temperature	<a href="#">[1]</a>	-	225	°C
$T_{case}$	case temperature	operating <a href="#">[1]</a>	-40	+125	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$V_{DS} = 28\text{ V}$ ; $I_{Dq} = 800\text{ mA}$ (main); $V_{GS(amp)peak} = 1.0\text{ V}$ ; $T_{case} = 80\text{ °C}$		
		$P_L = 56\text{ W}$	0.29	k/W
		$P_L = 74\text{ W}$	0.27	k/W

## 6. Characteristics

**Table 6. DC characteristics**

$T_j = 25\text{ °C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Main device</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 1.44\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 144\text{ mA}$	1.5	2.0	2.5	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 28\text{ V}; I_D = 800\text{ mA}$	-	2.2	-	V
$I_{DSS}$	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 32\text{ V}$	-	-	2.8	$\mu\text{A}$
$I_{DSX}$	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$	-	26.5	-	A
$I_{GSS}$	gate leakage current	$V_{GS} = 9\text{ V}; V_{DS} = 0\text{ V}$	-	-	280	nA
$g_{fs}$	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 7.2\text{ A}$	-	15.0	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 5.04\text{ A}$	-	93	128	$\text{m}\Omega$
<b>Peak device</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 2.98\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 298\text{ mA}$	1.5	2.0	2.5	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 28\text{ V}; I_D = 1600\text{ mA}$	-	2.2	-	V
$I_{DSS}$	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 32\text{ V}$	-	-	2.8	$\mu\text{A}$
$I_{DSX}$	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$	-	47	-	A
$I_{GSS}$	gate leakage current	$V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	280	nA
$g_{fs}$	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 14.9\text{ A}$	-	28.5	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 10.43\text{ A}$	-	50	74	$\text{m}\Omega$

**Table 7. RF characteristics**

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 to 64 DPCH;  $f_1 = 2112.5\text{ MHz}; f_2 = 2167.5\text{ MHz}$ ; RF performance at  $V_{DS} = 28\text{ V}; I_{Dq} = 800\text{ mA}$  (main);  $V_{GS(amp)peak} = 1.0\text{ V}; T_{case} = 25\text{ °C}$ ; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 2110 MHz to 2200 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$G_p$	power gain	$P_{L(AV)} = 56\text{ W}$	15.3	16.3	-	dB
$RL_{in}$	input return loss	$P_{L(AV)} = 56\text{ W}$	-	-14	-9	dB
$\eta_D$	drain efficiency	$P_{L(AV)} = 56\text{ W}$	42	46	-	%
ACPR	adjacent channel power ratio	$P_{L(AV)} = 56\text{ W}$	-	-29	-24	dBc

**Table 8. RF characteristics**

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 to 64 DPCH;  $f_1 = 2112.5\text{ MHz}; f_2 = 2167.5\text{ MHz}$ ; RF performance at  $V_{DS} = 28\text{ V}; I_{Dq} = 800\text{ mA}$  (main);  $V_{GS(amp)peak} = 1.0\text{ V}; T_{case} = 25\text{ °C}$ ; unless otherwise specified; in an asymmetrical Doherty production test circuit at a frequency of 2200 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$PAR_O$	output peak-to-average ratio	$P_{L(AV)} = 56\text{ W}$	6.3	6.9	-	dB
$P_{L(M)}$	peak output power	$P_{L(AV)} = 56\text{ W}$	380	440	-	W

## 7. Test information

### 7.1 Ruggedness in Doherty operation

The BLC10G22XS-400AVT is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS} = 32\text{ V}$ ;  $I_{Dq} = 800\text{ mA}$ ;  $V_{GS(amp)peak} = 1.0\text{ V}$ ;  $f = 2112.5\text{ MHz}$ ;  $P_L = 155\text{ W}$  (5 dB OBO); 100 % clipping

### 7.2 Impedance information

**Table 9. Typical impedance of main device**

Measured load-pull data of main device;  $I_{Dq} = 800\text{ mA}$  (main);  $V_{DS} = 28\text{ V}$ ; pulsed CW ( $t_p = 100\text{ }\mu\text{s}$ ;  $\delta = 10\text{ %}$ ).

f (MHz)	Z <sub>S</sub> [1] (Ω)	Z <sub>L</sub> [1] (Ω)	P <sub>L</sub> [2] (W)	η <sub>D</sub> [2] (%)	G <sub>p</sub> [2] (dB)
<b>Maximum power load</b>					
2110	1.6 – j6.1	1.5 – j2.9	205	61.5	17.2
2140	2.1 – j6.5	1.5 – j2.9	205	62.0	17.3
2170	2.6 – j7.0	1.4 – j3.3	205	60.0	17.2
<b>Maximum drain efficiency load</b>					
2110	1.6 – j6.1	2.4 – j2.4	160	68.0	19.1
2140	2.1 – j6.5	2.4 – j2.3	158	67.5	19.2
2170	2.6 – j7.0	2.0 – j2.2	160	67.0	19.1

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At 3 dB gain compression.

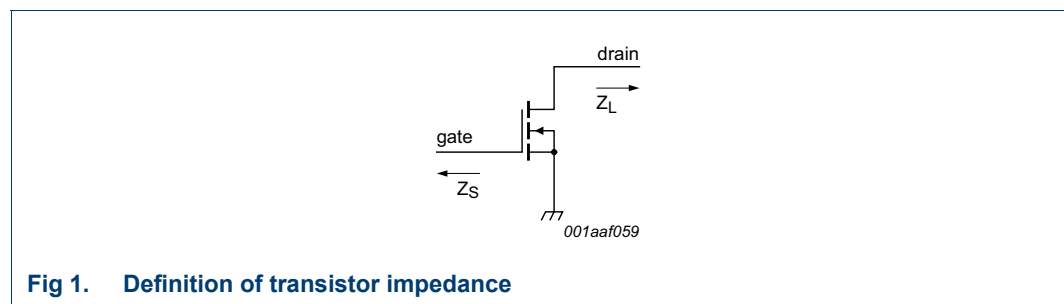
**Table 10. Typical impedance of peak device**

Measured load-pull data of peak device;  $I_{Dq} = 1600 \text{ mA (peak)}$ ;  $V_{DS} = 28 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu\text{s}$ ;  $\delta = 10 \%$ ).

f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]	P <sub>L</sub> [2]	η <sub>D</sub> [2]	G <sub>p</sub> [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
<b>Maximum power load</b>					
2110	1.9 – j5.4	1.3 – j3.3	390	60.0	16.2
2140	2.4 – j5.7	1.4 – j3.5	390	57.5	16.3
2170	3.1 – j6.1	1.3 – j3.7	390	55.0	16.1
<b>Maximum drain efficiency load</b>					
2110	1.9 – j5.4	1.8 – j2.7	340	63.6	17.6
2140	2.4 – j5.7	1.9 – j2.6	315	63.4	18.1
2170	3.1 – j6.1	1.9 – j2.7	320	63.6	18.2

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At 3 dB gain compression.



**Fig 1. Definition of transistor impedance**

### 7.3 Recommended impedances for Doherty design

**Table 11. Typical impedance of main at 1 : 1 load**

Measured load-pull data of main device;  $I_{Dq} = 800 \text{ mA (main)}$ ;  $V_{DS} = 28 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu\text{s}$ ;  $\delta = 10 \%$ ).

f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]	P <sub>L</sub> [2]	η <sub>D</sub> [2]	G <sub>p</sub> [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
2110	1.7 – j5.5	2.1 – j3.8	165	38.0	20.8
2140	2.0 – j5.8	2.1 – j3.5	170	38.0	20.8
2170	2.3 – j6.1	2.0 – j3.3	175	38.5	21.1

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At P<sub>L(AV)</sub> = 56 W.

**Table 12. Typical impedance of main device at 1 : 2.5 load**

Measured load-pull data of main device;  $I_{Dq} = 800 \text{ mA (main)}$ ;  $V_{DS} = 28 \text{ V}$ ; pulsed CW ( $t_p = 100 \text{ }\mu\text{s}$ ;  $\delta = 10 \%$ ).

f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]	P <sub>L</sub> [2]	$\eta_D$ [2]	G <sub>p</sub> [2]
(MHz)	( $\Omega$ )	( $\Omega$ )	(W)	(%)	(dB)
2110	1.7 – j5.5	3.6 – j0.8	85	53.2	23.5
2140	2.0 – j5.8	3.5 – j0.6	78	53.4	23.5
2170	2.3 – j6.1	3.3 – j0.4	70	53.2	24.0

[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At P<sub>L(AV)</sub> = 56 W.

**Table 13. Typical impedance of peak device at 1 : 1 load**

Measured load-pull data of peak device;  $I_{Dq} = 1600 \text{ mA (peak)}$ ;  $V_{DS} = 28 \text{ V}$ ; pulsed CW ( $t_p = 100 \text{ }\mu\text{s}$ ;  $\delta = 10 \%$ ).

f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]	P <sub>L</sub> [2]	$\eta_D$ [2]	G <sub>p</sub> [2]
(MHz)	( $\Omega$ )	( $\Omega$ )	(W)	(%)	(dB)
2110	1.7 – j4.8	1.8 – j3.5	350	25.5	19.7
2140	2.0 – j5.0	1.8 – j3.2	345	25.8	19.9
2170	2.4 – j5.2	1.8 – j3.1	340	26.4	20.4

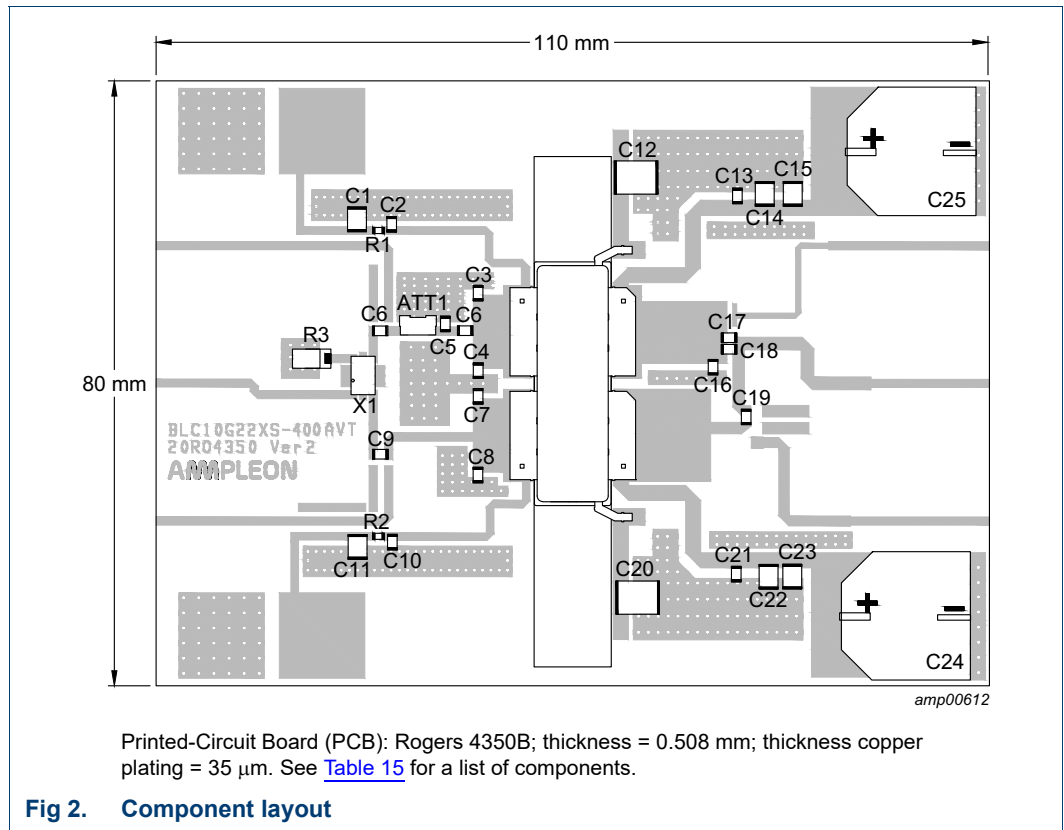
[1] Z<sub>S</sub> and Z<sub>L</sub> defined in [Figure 1](#).

[2] At P<sub>L(AV)</sub> = 56 W.

**Table 14. Off-state impedances of peak device**

f	Z <sub>off</sub>
(MHz)	( $\Omega$ )
2110	2.9 – j2.9
2140	2.3 – j1.8
2170	2.0 – j1.0

7.4 Test circuit

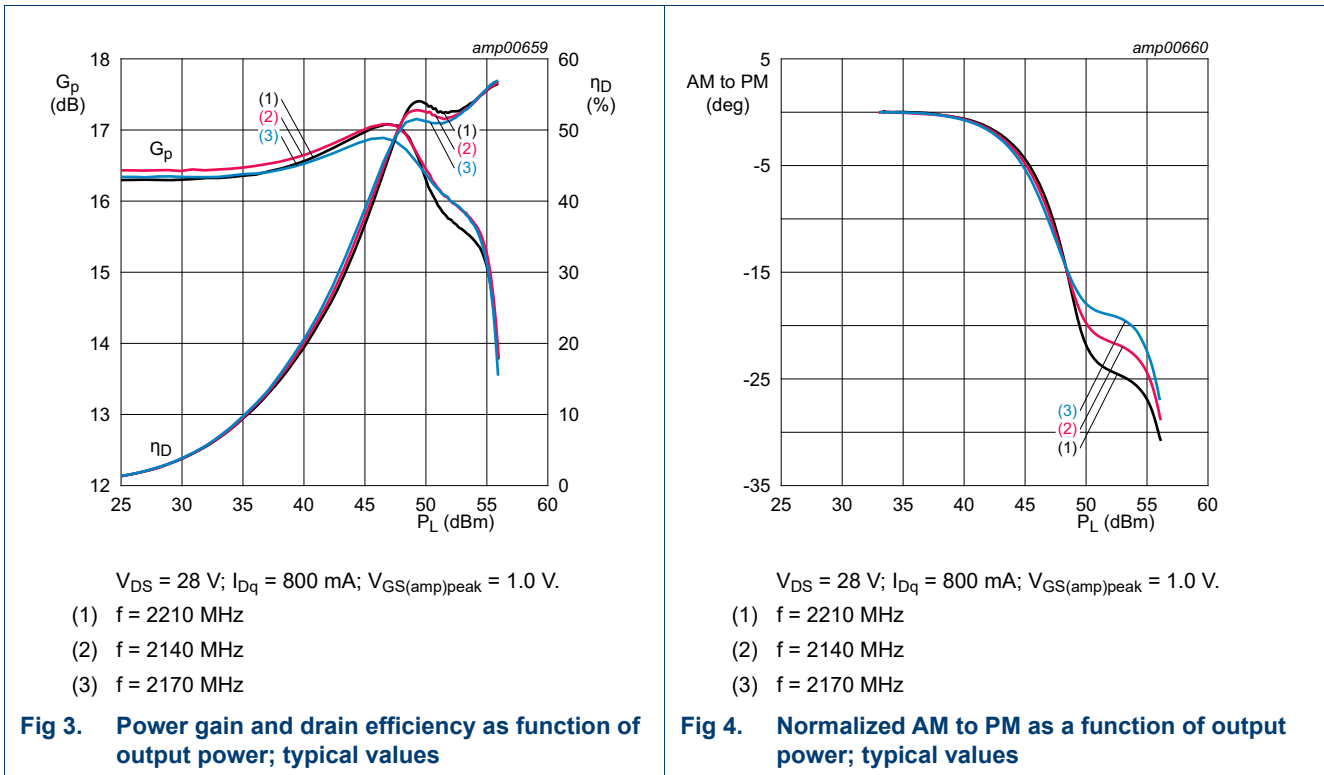


**Table 15. List of components**  
See [Figure 2](#) for component layout.

Component	Description	Value	Remarks
C1, C11, C14, C15, C22, C23,	multilayer ceramic chip capacitor	10 $\mu\text{F}$ , 50 V	Murata: GRM32ER71H106KA12L, SMD 1210
C2, C6, C9, C10, C13, C19, C21	multilayer ceramic chip capacitor	15 pF, 250 V	Murata: GQM2195C2E150FB15, SMD 805
C3, C4, C7, C8	multilayer ceramic chip capacitor	1.0 pF, 250 V	Murata: GQM2195C2E1ROBB15, SMD 0805
C5	multilayer ceramic chip capacitor	0.8 pF, 250 V	Murata: GQM2195C2E1ROBB15, SMD 0805
C12, C20	multilayer ceramic chip capacitor	4.7 $\mu\text{F}$ , 100 V	C5750X7R2A475KT/A
C16	multilayer ceramic chip capacitor	0.5 pF, 250 V	Murata: GQM2195C2E1ROBB15, SMD 0805
C17, C18	multilayer ceramic chip capacitor	1.8 pF, 250 V	Murata: GQM2195C2E1R8BB15, SMD 0805
C24, C25	electrolytic capacitor	470 $\mu\text{F}$ , 63 V	
R1, R2	resistor	5.1 $\Omega$ , 1 %	SMD 805
R3	resistor	50 $\Omega$ , 25 W	Anaren: C16A50Z4
X1	hybrid coupler	2 dB, 90°	Anaren: Xinger III, X3C20F1-02
ATT1	attenuator	1 dB	Anaren: D10AA1Z4

7.5 Graphical data

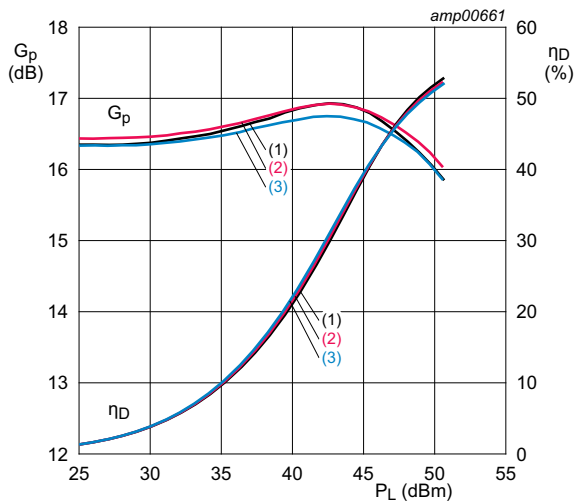
7.5.1 Pulsed CW





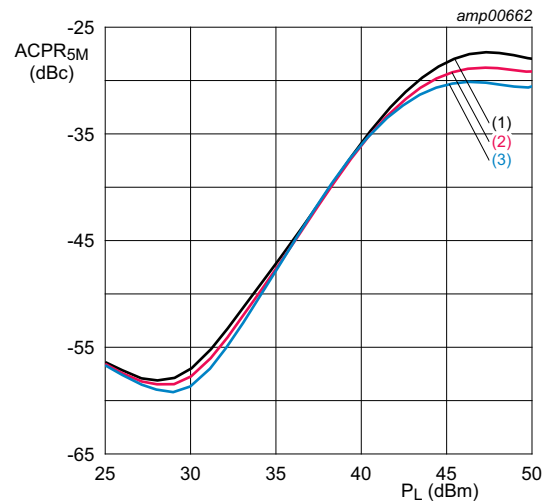
7.5.2 1-Carrier W-CDMA

Test signal: 3GPP test model 1; 1 to 64 DPCH (100 % clipping): PAR = 7.5 dB per carrier at 0.01 % probability on CCDF per carrier.



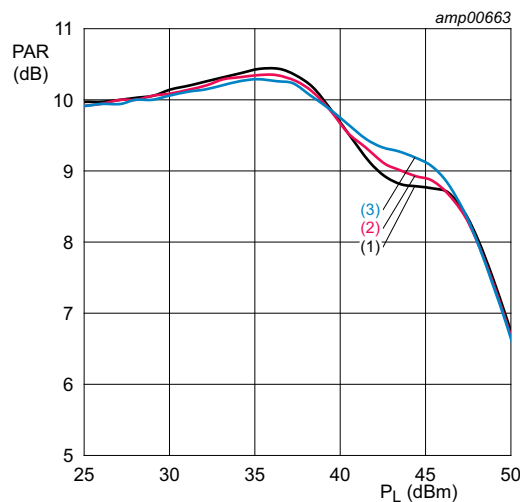
$V_{DS} = 28\text{ V}; I_{Dq} = 800\text{ mA}; V_{GS(amp)peak} = 1.0\text{ V}.$   
 (1)  $f = 2210\text{ MHz}$   
 (2)  $f = 2140\text{ MHz}$   
 (3)  $f = 2170\text{ MHz}$

Fig 5. Power gain and drain efficiency as function of output power; typical values



$V_{DS} = 28\text{ V}; I_{Dq} = 800\text{ mA}; V_{GS(amp)peak} = 1.0\text{ V}.$   
 (1)  $f = 2210\text{ MHz}$   
 (2)  $f = 2140\text{ MHz}$   
 (3)  $f = 2170\text{ MHz}$

Fig 6. Adjacent channel power ratio (5 MHz) as a function of output power; typical values

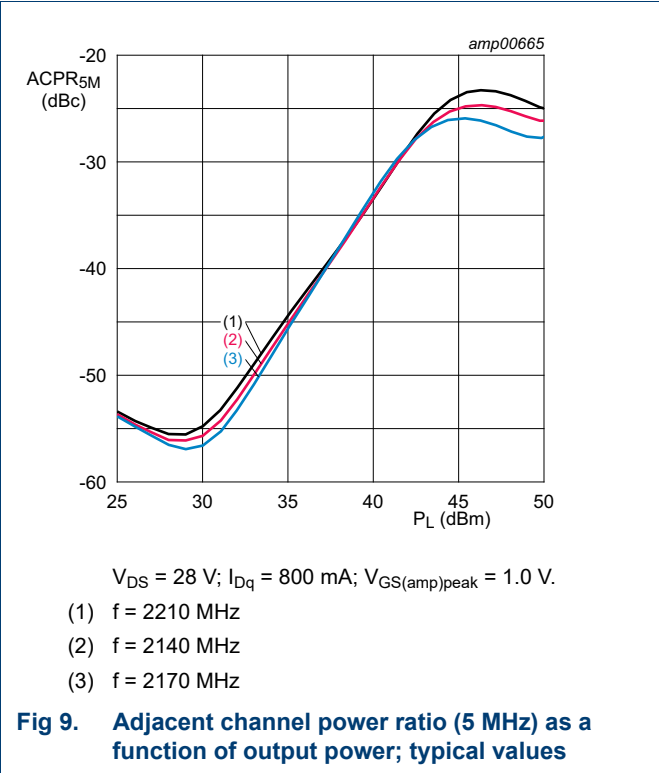
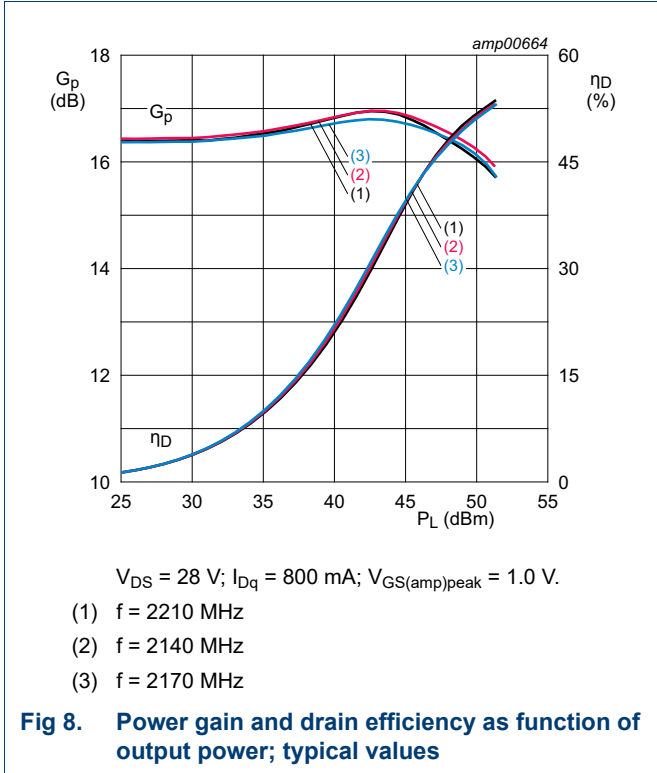


$V_{DS} = 28\text{ V}; I_{Dq} = 800\text{ mA}; V_{GS(amp)peak} = 1.0\text{ V}.$   
 (1)  $f = 2210\text{ MHz}$   
 (2)  $f = 2140\text{ MHz}$   
 (3)  $f = 2170\text{ MHz}$

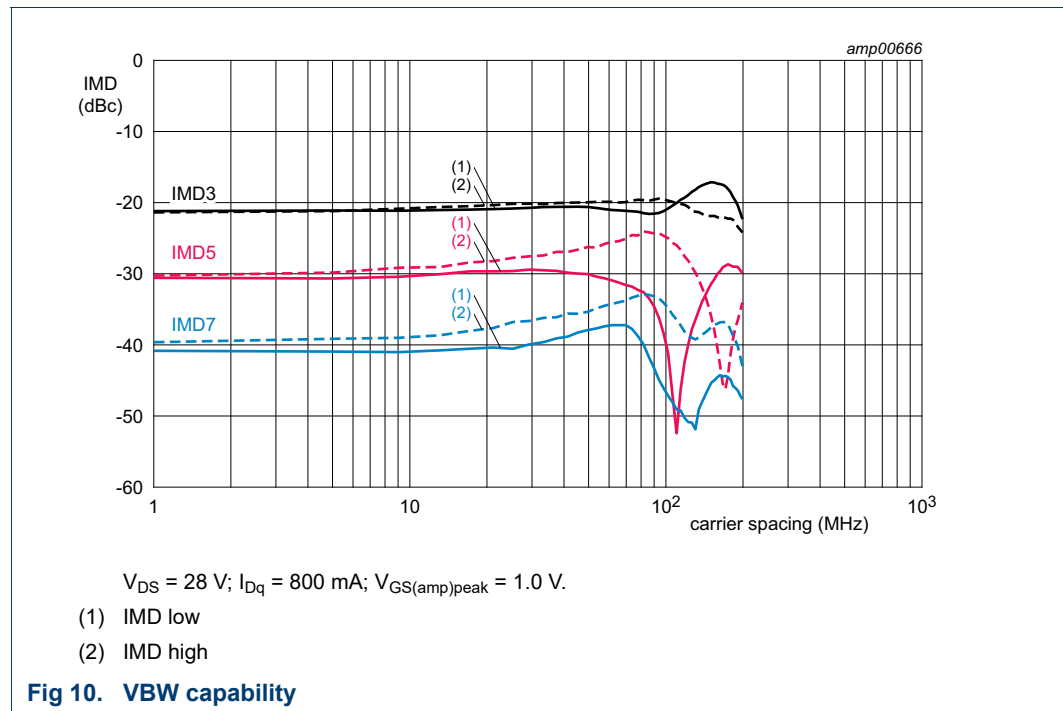
Fig 7. Peak-to-average power ratio as a function of output power; typical values

7.5.3 2-Carrier W-CDMA

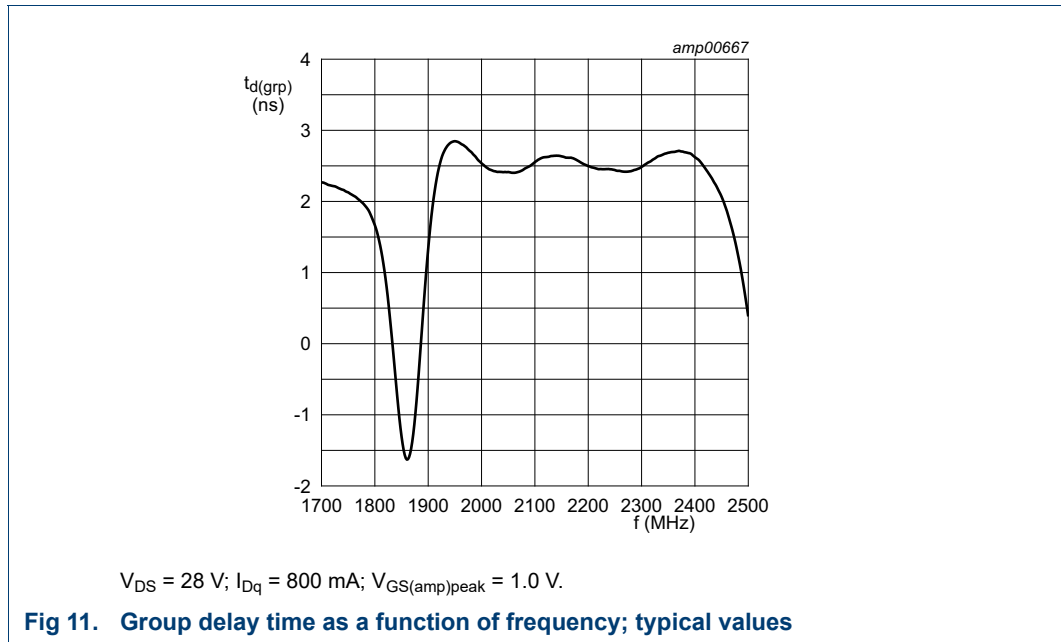
Test signal: 3GPP test model 1; 1 to 64 DPCH (46 % clipping): PAR = 7.5 dB per carrier at 0.01 % probability on CCDF per carrier.



7.5.4 2-Tone VBW



7.5.5 Group delay



### 8. Package outline

Air cavity plastic earless flanged package; 6 leads

SOT1258-4

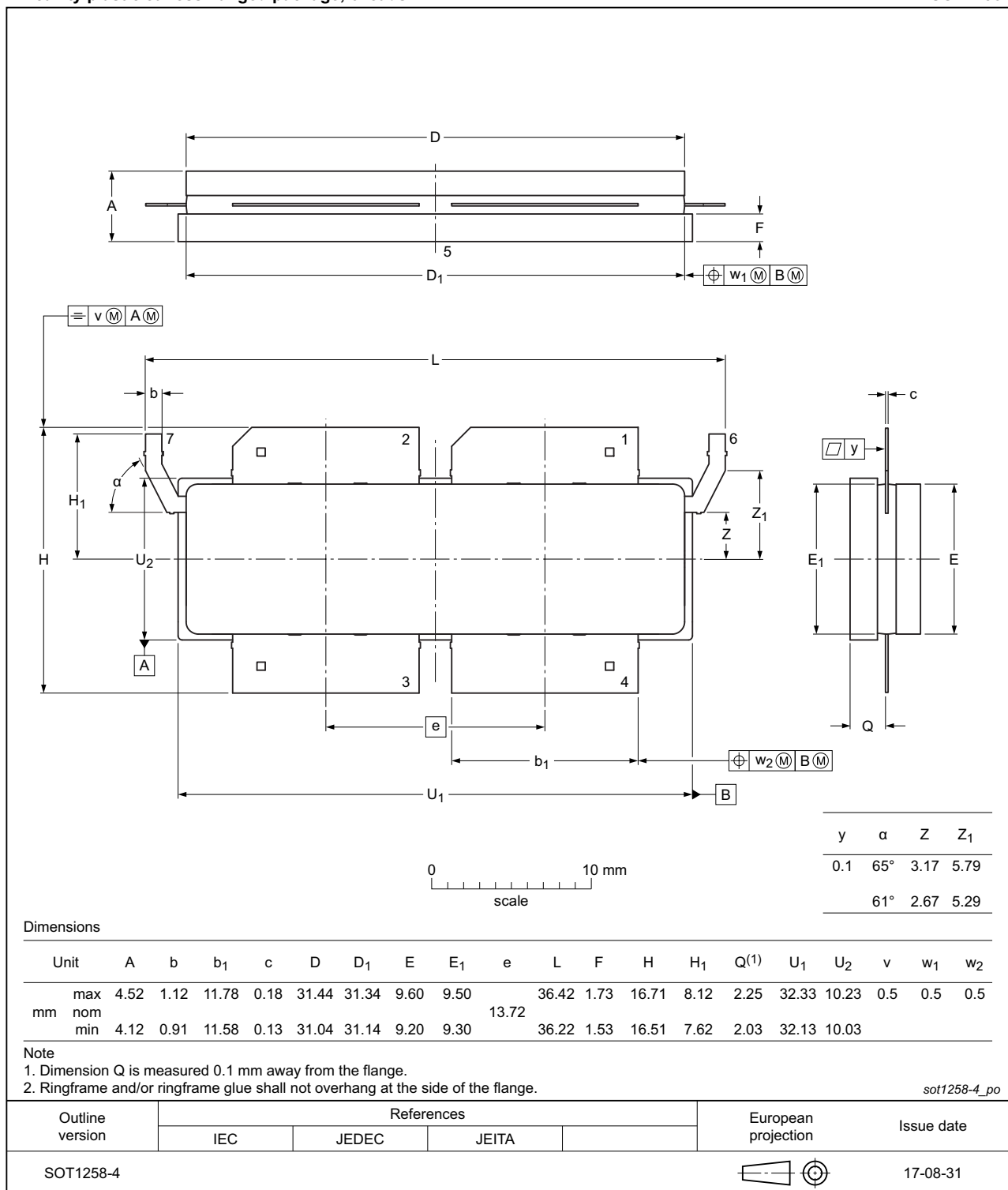



Fig 12. Package outline SOT1258-4

## 9. Handling information

CAUTION	
	<p>This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.</p> <p>Such precautions are described in the <i>ANSI/ESD S20.20</i>, <i>IEC/ST 61340-5</i>, <i>JESD625-A</i> or equivalent standards.</p>

**Table 16. ESD sensitivity**

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C3 <a href="#">[1]</a>
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 <a href="#">[2]</a>

- [1] CDM classification C3 is granted to any part that passes after exposure to an ESD pulse of 1000 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

## 10. Abbreviations

**Table 17. Abbreviations**

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
OBO	Output Back Off
PAR	Peak-to-Average Ratio
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

## 11. Revision history

**Table 18. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLC10G22XS-400AVT v.1	20180430	Product data sheet	-	-

## 12. Legal information

### 12.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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## 13. Contact information

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14. Contents

1 **Product profile** . . . . . 1

1.1 General description . . . . . 1

1.2 Features and benefits . . . . . 1

1.3 Applications . . . . . 1

2 **Pinning information** . . . . . 2

3 **Ordering information** . . . . . 2

4 **Limiting values** . . . . . 2

5 **Thermal characteristics** . . . . . 2

6 **Characteristics** . . . . . 3

7 **Test information** . . . . . 4

7.1 Ruggedness in Doherty operation . . . . . 4

7.2 Impedance information . . . . . 4

7.3 Recommended impedances for Doherty design 5

7.4 Test circuit . . . . . 7

7.5 Graphical data . . . . . 8

7.5.1 Pulsed CW . . . . . 8

7.5.2 1-Carrier W-CDMA . . . . . 9

7.5.3 2-Carrier W-CDMA . . . . . 10

7.5.4 2-Tone VBW . . . . . 10

7.5.5 Group delay . . . . . 11

8 **Package outline** . . . . . 12

9 **Handling information** . . . . . 13

10 **Abbreviations** . . . . . 13

11 **Revision history** . . . . . 13

12 **Legal information** . . . . . 14

12.1 Data sheet status . . . . . 14

12.2 Definitions . . . . . 14

12.3 Disclaimers . . . . . 14

12.4 Trademarks . . . . . 15

13 **Contact information** . . . . . 15

14 **Contents** . . . . . 16

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